L Number	Hits	Search Text	DB	Time stamp
1	276695	257/$.ccls. 438./$.ccls. 365/$.ccls	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 09:46
2	17760	(257/$.ccls. 438./$.ccls. 365/$.ccls) and (memory with substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 10:29
3	95	((257/$.ccls. 438./$.ccls. 365/$.ccls) and (memory with substrate)) and ((((bottom lower top upper) near electrode$1) with (perovskite (colossal near magnetoresistance (CMR))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 10:11
4	194	(257/$.ccls. 438./$.ccls. 365/$.ccls) and (((bottom lower top upper) near electrode$1) with (perovskite (colossal near magnetoresistance (CMR))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 10:29
5	50084	memory with substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 10:29
6	139	(memory with substrate) and (((bottom lower top upper) near electrode$1) with (perovskite (colossal near magnetoresistance (CMR))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 10:59
7	4	("5508953" | "5579258" | "6128214" | "6204139").PN.	USPAT	2004/06/21 10:42
8	17	(memory with substrate) and (etch$3 near2 (open$3 hole via$1) near2 ((bottom lower) near electrode$1))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 11:20
9	619	(memory with substrate) and ((insulat$3 isolat$3) near2 ((bottom lower) near electrode$1))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 11:31
10	23	((memory with substrate) and ((insulat$3 isolat$3) near2 ((bottom lower) near electrode$1))) and (etch$3 near2 (open$3 hole via$1) near2 (insulat$ isolat$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 11:31
11	3021	((insulat$3 isolat$3) near2 ((bottom lower) near electrode$1))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 11:31
12	61	(((insulat$3 isolat$3) near2 ((bottom lower) near electrode$1))) and (etch$3 near2 (open$3 hole via$1) near2 (insulat$ isolat$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 11:31

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